	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
1	BRS	L1	21918	floating adj gate$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/22 16:26			0
2	BRS	L2	101982	polyimid$3 or poly-imid$3 or (poly adj imid$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/22 16:29			0
3	BRS	L3	104	1 and 2	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/22 15:05			0
4	BRS	L4	793	passivat$4 same ((silicon adj nitride) or Si3N4 or "Si3N4" or SiN$1 or "Si.sub.3N.sub.4" or "Si.sub.3 N.sub.4") same 2	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/22 15:07			0
5	BRS	L5	9	1 and 4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/22 15:07			0
6	BRS	L6	11	((floating adj gate$1) with (micron$1 or angstrom$1)) and 2	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/22 16:13			0
7	BRS	L7	1	4 and ((floating adj gate$1) near15 (length or width))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/22 16:30			0

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
8	BRS	L8	1	4 and ((floating adj gate$1) with (length or width))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/22 16:28			0
9	BRS	L9	4974	(polyimid$3 or poly-imid$3 or (poly adj imid$3)) same ((silicon adj nitride) or Si3N4 or "Si3N4" or SiN$1 or "Si.sub.3N.sub.4" or "Si.sub.3 N.sub.4")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/22 16:30			0
10	BRS	L11	4	9 and 10	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/22 16:30			0
11	BRS	L10	1480	(floating adj gate$1) near15 (length or width)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/22 16:38			0
12	BRS	L12	119	(floating adj gate$1) with (length or width) with (nm or micron$1 or "nm" or micron$1 or angstrom$1 or nanometer$1 or namometre$1 or (nano adj met$4))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/22 16:44			0